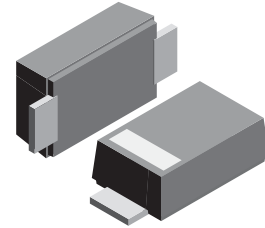


VOLTAGE RANGE: 20 - 40V
CURRENT: 1.0 A

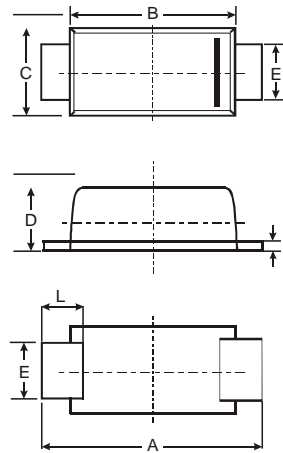
Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O



Mechanical Data

- Case: SOD-123FL
plastic body over passivated junction
- Terminals : Plated axial leads,
- solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Mounting Position : Any
- Weight: 0.0007 ounce, 0.02 grams



SOD-123FL			
Dim	Min	Max	Typ
A	3.50	3.80	3.65
B	2.60	2.90	2.75
C	1.70	1.90	1.80
D	0.09	1.10	1.00
E	0.08	1.10	0.095
H	0.12	0.20	0.16
L	0.07	0.09	0.08
All Dimensions in mm			

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SL02	SL03	SL04	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{VRWM} V _R	20	30	40	V
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	V
Average Rectified Output Current @T _L = 75°C	I _O	1.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30			A
Forward Voltage @I _F = 1.0A	V _{FM}	0.38	0.38	0.40	V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	0.5 20			mA
Typical Thermal Resistance Junction to Ambient (Note 1)	R _{θJA}	88			K/W
Operating Temperature Range	T _j	-65 to +125			°C
Storage Temperature Range	T _{STG}	-65 to +150			°C

Note: 1. Mounted on P.C. Board with 5.0mm² (0.13mm thick) copper pad areas

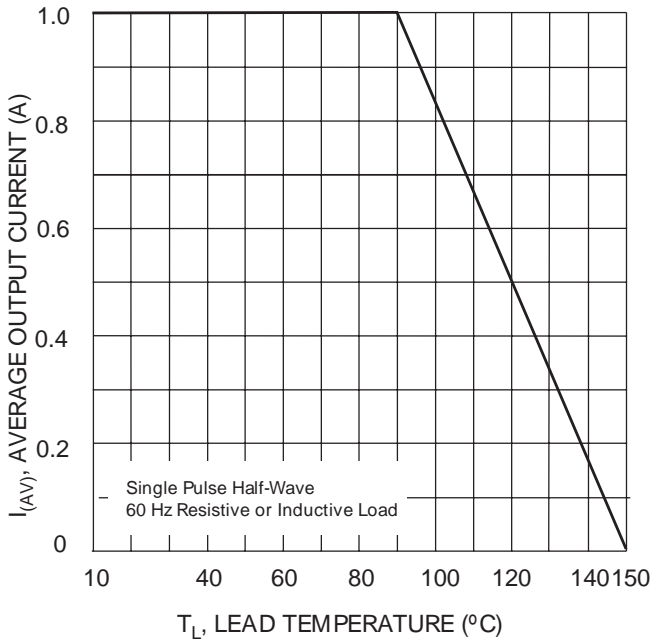


Fig. 1 Forward Current Derating Curve

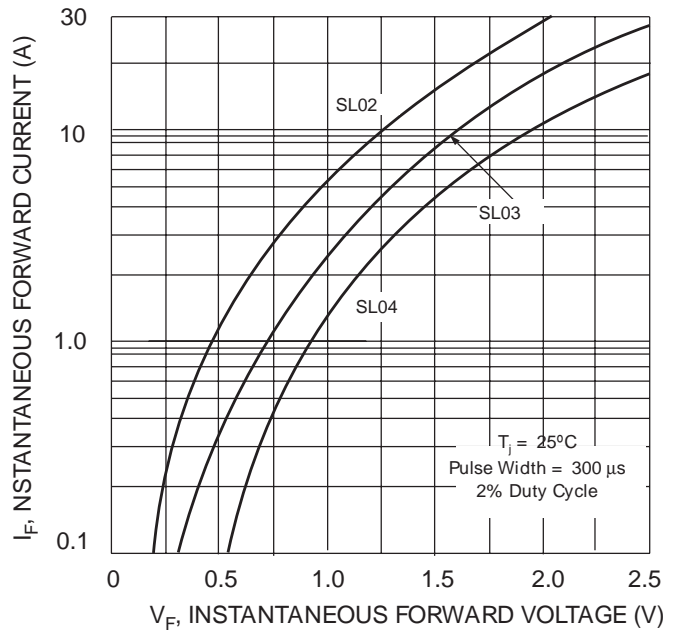


Fig. 2 Typical Forward Characteristics

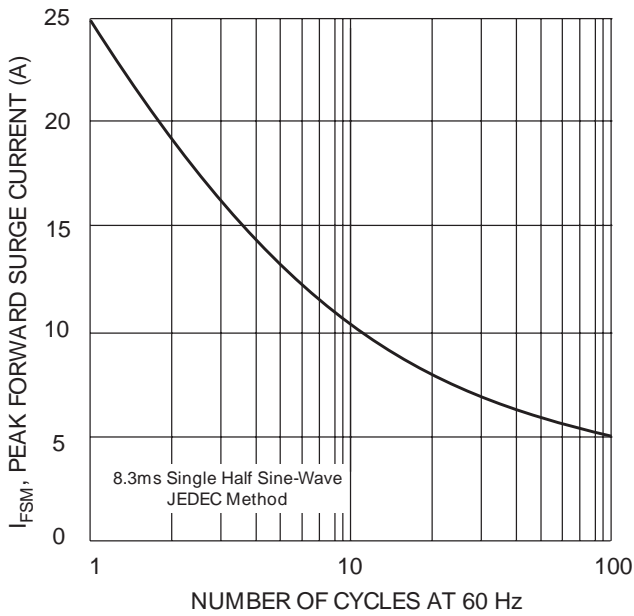


Fig. 3 Maximum Non-Repetitive Peak Fwd Surge Current

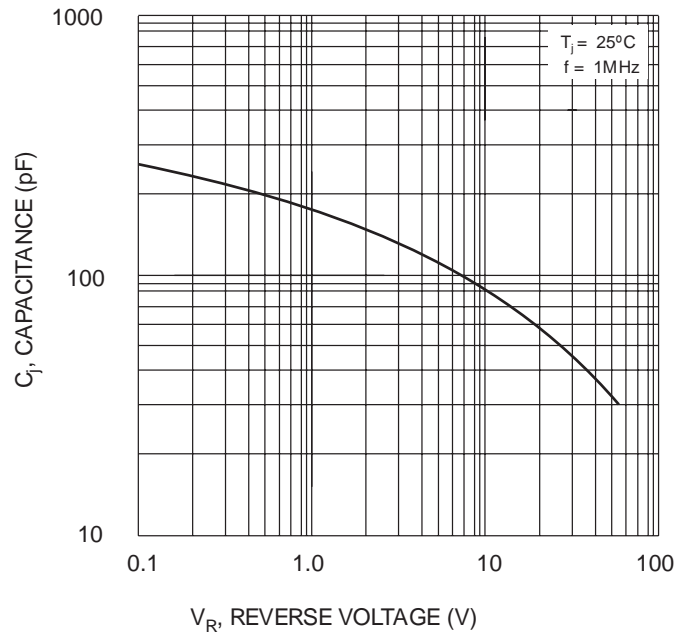


Fig. 4 Typical Junction Capacitance